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Pages: 21 including cover sheet

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Date: 4/4/2003

Re: Serial No. 10/055,138
Filing Date: January 23, 2002
IBM Ref: YOR920010499US1
Our Docket: 14710

CC:

XX Urgent ☐ **For Review** ☐ **Please Comment** ☐ **Please Reply** ☐ **Please Recycle**

Dear Sir:

The following is attached hereto:

1. General Transmittal in duplicate
2. Statement of Correction of Inventorship under 37 CFR 1.48(a)(1)
3. Statement of Inventorship under 37 CFR 1.48(a)(2)
4. Declaration and Power of Attorney
5. Assignment with recordal in duplicate
6. Assent of Assignee to Correction and Addition to Inventors
7. Letter of Authority
8. Statement under 37 CFR 3.73(b)
9. Authorization to charge deposit acct. 50-0510/IBM (\$ 130.00; 40.00)
10. Certificate of Facsimile in duplicate

for:

Applicants: Stephen W. Bedell, et al.

Serial No.: 10/055,138

Filed: January 23, 2003

Title: METHOD OF CREATING HIGH-QUALITY RELAXED SiGe-ON-INSULATOR
FOR STRAINED Si CMOS APPLICATIONS

Docket: YOR920010499US1 (14710)

Dated: April 4, 2003


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CERTIFICATE OF TRANSMISSION BY FACSIMILE (37 CFR 1.8)			Docket No.	
Applicant(s): Stephen W. Bedell, et al.			YOR920010499US1 (14710)	
Serial No. 10/055,138	Filing Date 1/23/2002	Examiner Tho Luu	Group Art Unit 2824	
Invention: METHOD OF CREATING HIGH-QUALITY RELAXED SiGe-ON-INSULATOR FOR STRAINED Si CMOS APPLICATIONS				
<p>I hereby certify that this <u>Bundle for Correction of Inventorship</u> (Identify type of correspondence)</p> <p>is being facsimile transmitted to the United States Patent and Trademark Office (Fax. No. <u>703-305-1341</u>)</p> <p>on <u>April 4, 2003</u> (Date)</p> <p><u>Susan Formicola</u> (Typed or Printed Name of Person Signing Certificate)</p> <p><u>Susan Formicola</u> (Signature)</p>				
Note: Each paper must have its own certificate of mailing.				

TRANSMITTAL LETTER
(General - Patent Pending)Docket No.
YOR920010499US1 (14710)In Re Application Of: **Stephen W. B dell, et al.**Serial No.
10/055,138Filing Date
10/23/2002Examiner
Tho LuuGroup Art Unit
2824Title: **METHOD OF CREATING HIGH-QUALITY RELAXED SiGe-ON-INSULATOR FOR STRAINED Si CMOS APPLICATIONS****TO THE COMMISSIONER OF PATENTS AND TRADEMARKS:**Transmitted herewith is: **Letter of Authority; and Statement under 37 CFR 3.73 (b)****Statement for Correction of Inventorship under 37 CFR 1.48(a)(1)****Statement of Inventorship under 37 CFR 1.48(a)(2)****Declaration and Power of Attorney****Assignment with Recordal (in dupl.)****Assent of Assignee to Correction and Addition of Inventors**

in the above identified application.

- ☐ No additional fee is required.
- ☐ A check in the amount of _____ is attached.
- ☒ The Commissioner is hereby authorized to charge and credit Deposit Account No. **50-0510/IBM** as described below. A duplicate copy of this sheet is enclosed.
- ☒ Charge the amount of **\$130.00**
- ☒ Credit any overpayment.
- ☒ Charge any additional fee required.


SignatureDated: **April 4, 2003****Leslie S. Szivos**
Registration No. 39,394
SCULLY, SCOTT, MURPHY & PRESSER
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Garden City, New York 11530
(516) 742-4343

I certify that this document and fee is being deposited on 4/4/2003 with the U.S. Postal Service as first class mail under 37 C.F.R. 1.8 and is addressed to the Commissioner of Patents and Trademarks, Washington, D.C. 20231.


Signature of Person Mailing Correspondence**Susan Formicola**

Typed or Printed Name of Person Mailing Correspondence

cc:

PATENTS

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**Applicant(s):** Stephen W. Bedell, et al.**Examiner:** Tho Luu**Serial No:** 10/055,138**Art Unit:** 2824**Filed:** January 23, 2002**Docket:** YOR920010499US1 (14710)**For:** METHOD OF CREATING
HIGH-QUALITY RELAXED
SiGe-ON-INSULATOR FOR STRAINED
Si CMOS APPLICATIONS**Dated:** April 4, 2003Commissioner for Patents
United States Patent and Trademark Office
Washington, D.C. 20231**STATEMENT FOR CORRECTION OF
INVENTORSHIP UNDER 37 C.F.R. §1.48(a)(1)**

Sir:

This is a statement for correction of inventorship in the above-identified patent application.

Enclosed herewith is:

A Statement of Inventorship under 37 C.F.R. §1.48(a)(2), signed by John Albrecht Ott.

CERTIFICATION OF FACSIMILE TRANSMISSION

I hereby certify that this paper is being facsimile transmitted to the Patent and Trademark Office on the date shown below.

Dated: April 4, 2003
Susan Formicola

A new oath, made under 37 C.F.R. §1.63, and assignment executed by the six (6) inventors of the claimed subject matter, Stephen W. Bedell, Jack O. Chu, Keith E. Fogel, Steven J. Koester, Devendra K. Sadana and John Albrecht Ott.

A Consent of Assignee to Correct Inventorship signed by an officer of the assignee of the present application.

Applicants give authorization to charge Deposit Account No. 50-0510 in the amount of \$130.00 pursuant to 37 C.F.R. §1.48(a)(4) and 37 C.F.R. §1.17(i). In the event any other fees are required to be submitted or a refund is due to the applicants, kindly charge or credit Deposit Account No. 50-0510. A duplicate copy of this document is enclosed.

Respectfully submitted,



Leslie S. Szivos
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LSS:gc/sf
Enclosures